

TRENCHSTOP[™] Series

Thermal Resistance

Parameter	Symbol	Conditions	Max. Value	Unit
Characteristic				L. C.
IGBT thermal resistance,	R _{thJC}		1.7	K/W
junction – case				
Thermal resistance,	R _{thJA}		62	
junction – ambient				

Electrical Characteristic, at T_j = 25 °C, unless otherwise specified

Parameter	Cumb al	Conditions	Value			11
	Symbol Conditions	min.	typ.	max.	Unit	
Static Characteristic						
Collector-emitter breakdown voltage	V _{(BR)CES}	V _{GE} =0V, I _C =0.25mA	600	-	-	V
Collector-emitter saturation voltage	V _{CE(sat)}	$V_{\rm GE} = 15 V, I_{\rm C} = 6 A$				
		<i>T</i> _j =25°C	-	1.5	2.05	
		<i>T</i> _j =175°C	-	1.8		
Gate-emitter threshold voltage	V _{GE(th)}	<i>I</i> _C =0.18mA,	4.1	4.6	5.7	
		$V_{\rm CE} = V_{\rm GE}$				
Zero gate voltage collector current	I _{CES}	V _{CE} =600V, V _{GE} =0V				μA
		<i>T</i> _j =25°C	-	-	40	
		<i>T</i> _j =175°C	-	-	700	
Gate-emitter leakage current	I _{GES}	$V_{CE}=0V, V_{GE}=20V$	-	-	100	nA
Transconductance	g _{fs}	$V_{\rm CE} = 20 V, I_{\rm C} = 6 A$	-	3.6	-	S
Integrated gate resistor	R _{Gint}			none		Ω

Dynamic Characteristic

Input capacitance	Ciss	V _{CE} =25V,	-	368	-	pF
Output capacitance	Coss	$V_{GE}=0V$,	-	28	-	
Reverse transfer capacitance	Crss	f=1MHz	-	11	-	
Gate charge	Q _{Gate}	$V_{\rm CC} = 480 \text{V}, \ I_{\rm C} = 6 \text{A}$	-	42	-	nC
		$V_{GE}=15V$				
Internal emitter inductance	LE		-	7	-	nH
measured 5mm (0.197 in.) from case						
Short circuit collector current ¹⁾	I _{C(SC)}	$V_{\rm GE} = 15 V, t_{\rm SC} \le 5 \mu s$ $V_{\rm CC} = 400 V,$	-	55	-	A
		$T_j = 25^{\circ}C$				

¹⁾ Allowed number of short circuits: <1000; time between short circuits: >1s.



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Switching Characteristic, Inductive Load, at $T_i=25$ °C

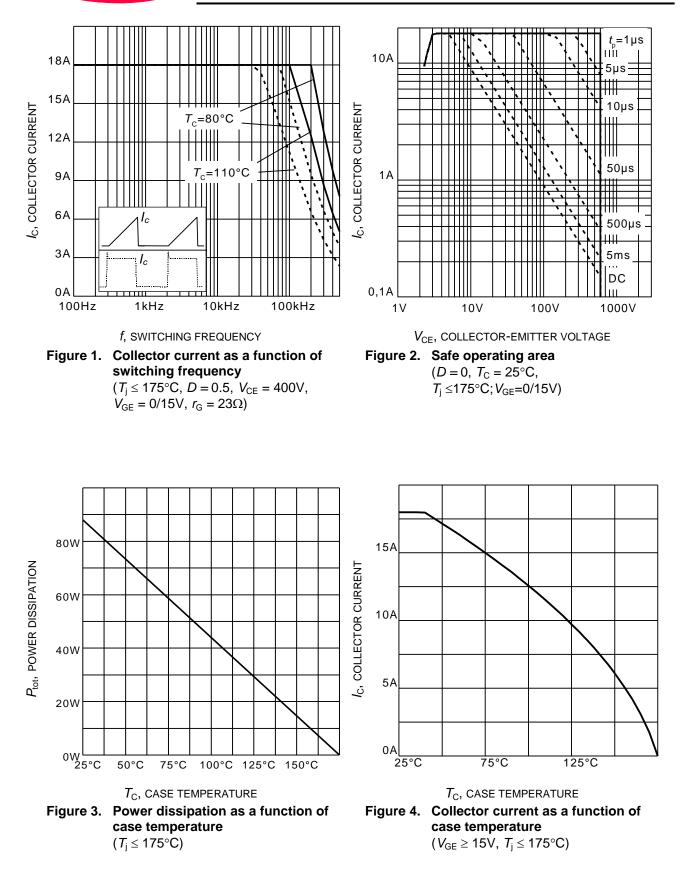
Parameter	Cymhol	Symbol Conditions	Value			11
	Symbol		min.	typ.	max.	Unit
IGBT Characteristic	·	·				
Turn-on delay time	$t_{d(on)}$	$T_{j}=25^{\circ}C,$ $V_{CC}=400V, I_{C}=6A,$ $V_{GE}=0/15V, r_{G}=23\Omega,$ $L_{\sigma}=60nH, C_{\sigma}=40pF$	-	9	-	ns
Rise time	t _r		-	6	-	
Turn-off delay time	$t_{d(off)}$		-	130	-	
Fall time	t _f		-	58	-	
Turn-on energy	Eon	L_{σ} , C_{σ} from Fig. E Energy losses include "tail" and diode reverse recovery. Diode used IDP06E60	-	0.09	-	mJ
Turn-off energy	E _{off}		-	0.11	-	7
Total switching energy	E _{ts}		-	0.2	-	

Switching Characteristic, Inductive Load, at T_j =175 °C

Parameter	Symbol	Conditions	Value			l Init
	Symbol	Conditions	min.	typ.	max.	Unit
IGBT Characteristic						
Turn-on delay time	$t_{d(on)}$	$T_{j}=175 ^{\circ}C,$ $V_{CC}=400 ^{\circ}V, I_{C}=6 ^{\circ}A,$ $V_{GE}=0/15 ^{\circ}V, r_{G}=23 ^{\circ}\Omega$ $L_{\sigma}=60 ^{\circ}H, C_{\sigma}=40 ^{\circ}PF$ L_{σ}, C_{σ} from Fig. E Energy losses include "tail" and diode reverse recovery. Diode used IDP06E60	-	9	-	ns
Rise time	tr		-	8	-	
Turn-off delay time	$t_{d(off)}$		-	165	-	
Fall time	t _f		-	84	-	
Turn-on energy	Eon		-	0.14	-	mJ
Turn-off energy	E _{off}		-	0.18	-	
Total switching energy	E _{ts}		-	0.335	-	

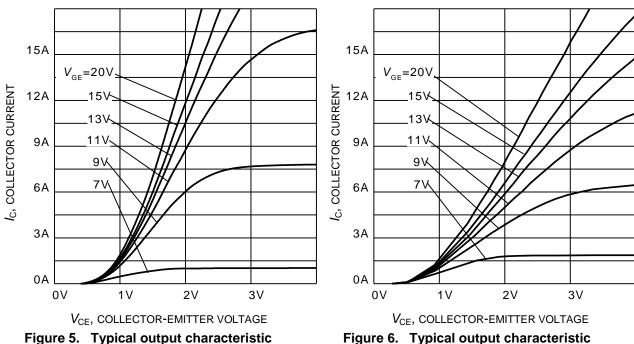


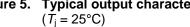


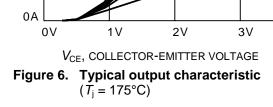


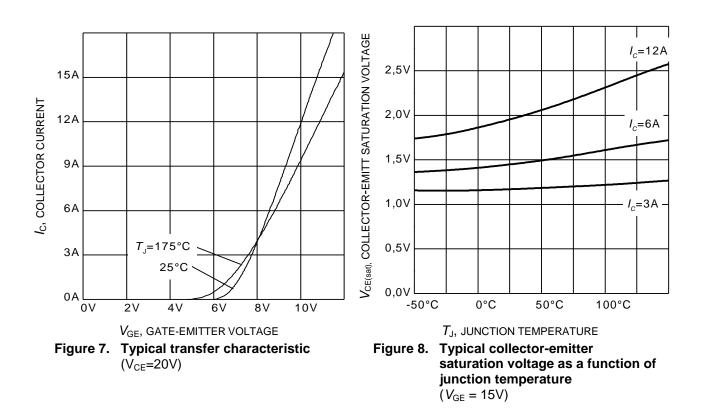






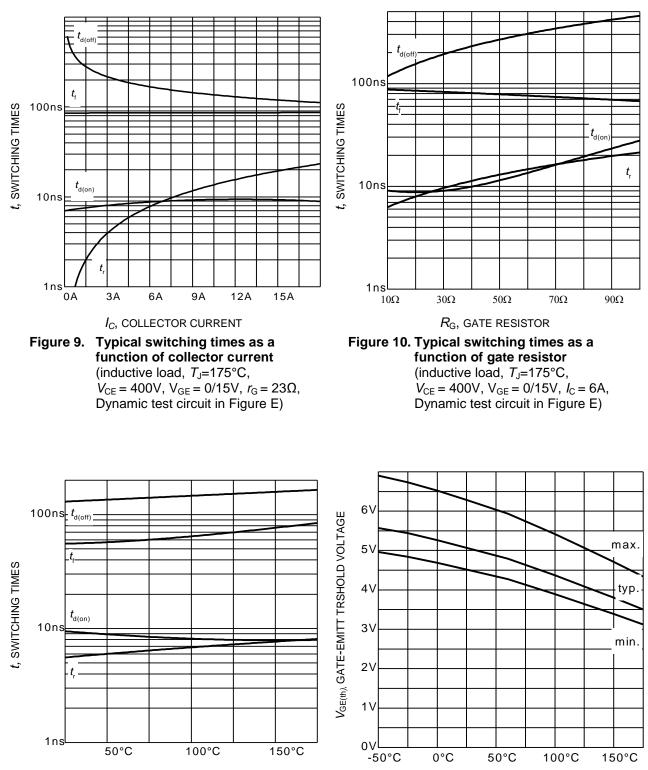






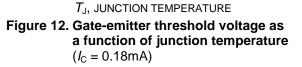


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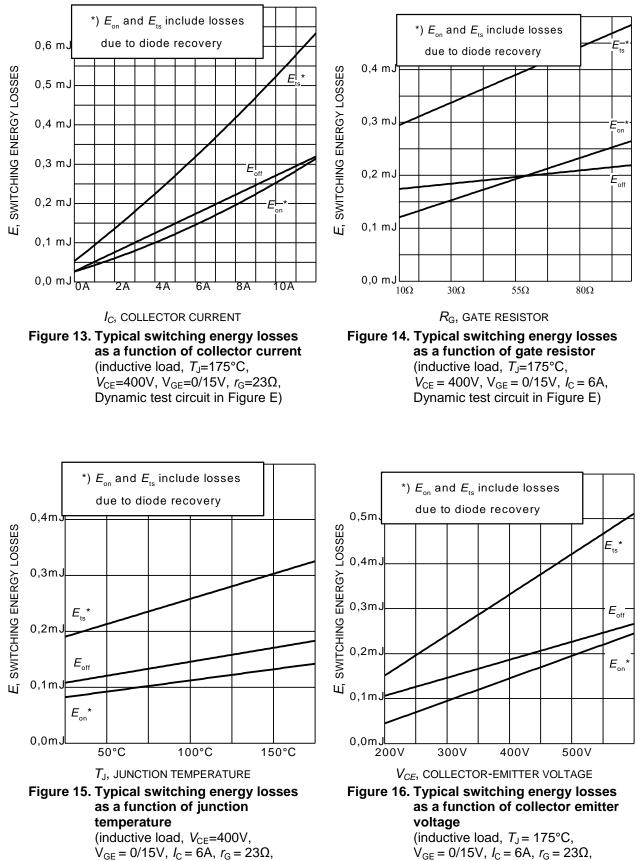
 $T_{\rm J}$, JUNCTION TEMPERATURE

Figure 11. Typical switching times as a function of junction temperature (inductive load, $V_{CE} = 400$ V, $V_{GE} = 0/15$ V, $I_C = 6$ A, $r_G = 23\Omega$, Dynamic test circuit in Figure E)





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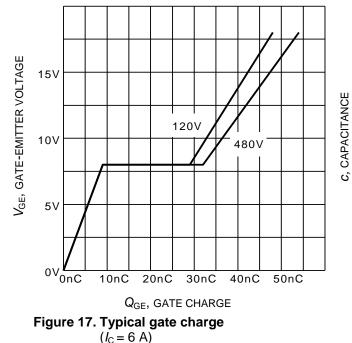


Dynamic test circuit in Figure E)

Dynamic test circuit in Figure E)







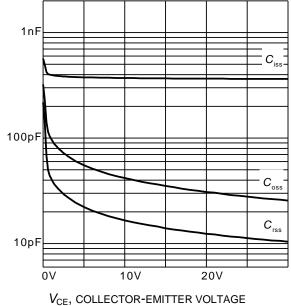
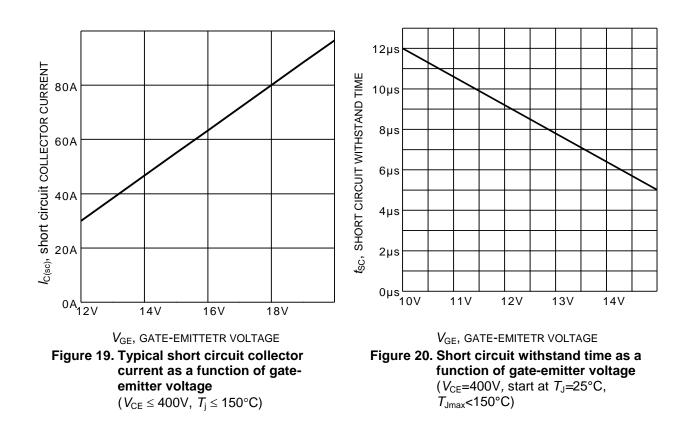
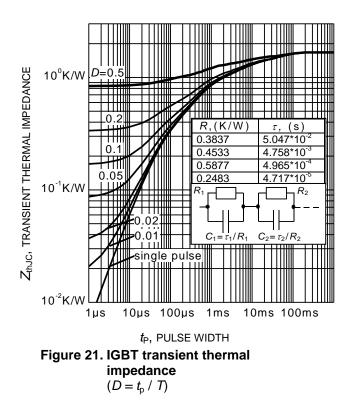


Figure 18. Typical capacitance as a function of collector-emitter voltage $(V_{GE}=0V, f = 1 \text{ MHz})$





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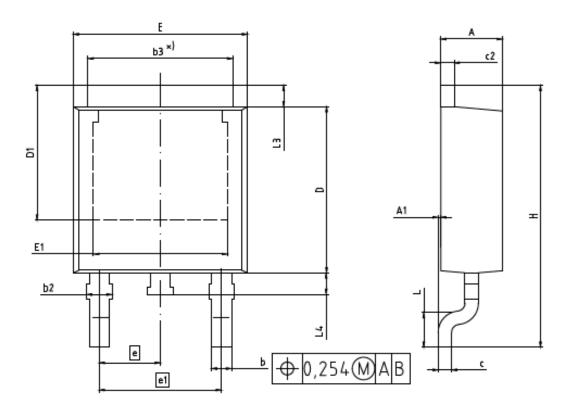


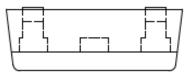
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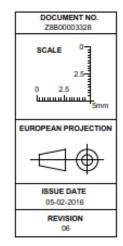
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Package Drawing PG-TO252-3





NOTES: 1. ALL DIMENSIONS REFER TO JEDEC STANDARD TO-252 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

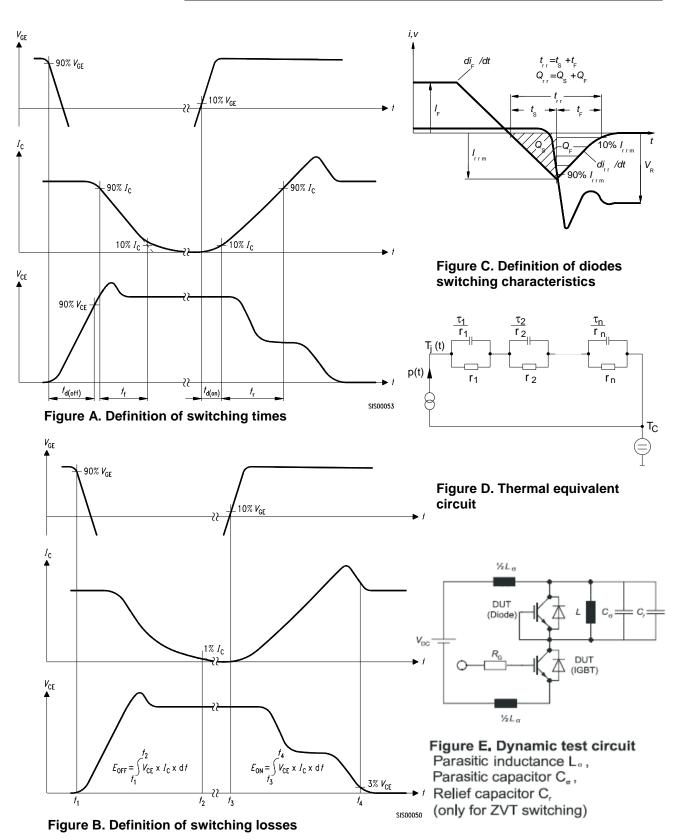


DIM	MILLIMETERS			
Long.	MIN	MAX		
A	2.16	2.41		
A1	0.00	0.15		
b	0.64	0.89		
b2	0.65	1.15		
b3	4,95	5.50		
c	0.46	0.61		
c2	0.40	0.98		
D	5.97	6.22		
D1	5.02	5.84		
E	6.35	6.73		
E1	4.32	5.21		
e	2	29 (BSC)		
e1	4.	.57 (BSC)		
N		3		
н	9.40	10.48		
L	1.18	1.78		
L3	0.89	1.27		
L4	0.51 1.02			

IFAG IPC TD VLS







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IGD06N60T



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